

NCE3080IA

Pb Free Product

NCE N-Channel Enhancement Mode Power MOSFET

Description

The NCE3080IA uses advanced trench technology and design to provide excellent R_{DS(ON)} with low gate charge. It can be used in a wide variety of applications.

General Features

V_{DS} =30V,I_D =80A

 $R_{DS(ON)}$ <6.5m Ω @ V_{GS} =10V

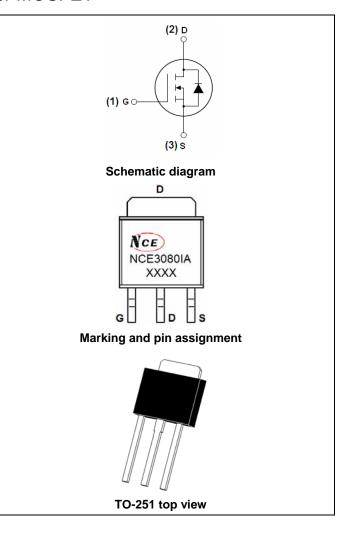
 $R_{DS(ON)}$ < 10m Ω @ V_{GS} =5V

- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Good stability and uniformity with high E_{AS}
- Excellent package for good heat dissipation

Application

- Power switching application
- Hard switched and high frequency circuits
- Uninterruptible power supply

100% UIS TESTED!



Package Marking and Ordering Information

	<u> </u>				
Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCE3080IA	NCE3080IA	TO-251	-	-	-

Absolute Maximum Ratings (T_C=25 ℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V _{DS}	30	V
Gate-Source Voltage	V _{GS}	±20	V
Drain Current-Continuous	I _D	80	А
Drain Current-Continuous(T _C =100°C)	I _D (100℃)	50	Α
Pulsed Drain Current	I _{DM}	170	А
Maximum Power Dissipation	P _D	83	W
Derating factor		0.56	W/℃
Single pulse avalanche energy (Note 5)	E _{AS}	306	mJ
Operating Junction and Storage Temperature Range	T_{J} , T_{STG}	-55 To 175	$^{\circ}\!\mathbb{C}$



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Thermal Characteristic

Electrical Characteristics (T_C=25 °C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit	
Off Characteristics	<u> </u>		•				
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250μA	30	-	-	V	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =30V,V _{GS} =0V	-	-	1	μΑ	
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±20V,V _{DS} =0V -		-	±100	nA	
On Characteristics (Note 3)	·						
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_{D}=250\mu A$	1	1.1	1.4	V	
Dunin Course On State Besistance	Б	V _{GS} =10V, I _D =30A	-	5.5	6.5	m0	
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =5V, I _D =24A -		7.5	10	mΩ	
Forward Transconductance	g FS	V _{DS} =5V,I _D =24A	20	-	-	S	
Dynamic Characteristics (Note4)	•		•			•	
Input Capacitance	C _{lss}	\/ -45\/\/ -0\/	-	2330	-	PF	
Output Capacitance	C _{oss}	V_{DS} =15V, V_{GS} =0V, F=1.0MHz	-	460	-	PF	
Reverse Transfer Capacitance	C _{rss}	F=1.UIVIDZ	-	230	-	PF	
Switching Characteristics (Note 4)	<u>.</u>						
Turn-on Delay Time	t _{d(on)}		-	20	-	nS	
Turn-on Rise Time	t _r	V _{DD} =10V,I _D =30A	-	15	-	nS	
Turn-Off Delay Time	t _{d(off)}	V_{GS} =10 V , R_{GEN} =2.7 Ω	-	60	-	nS	
Turn-Off Fall Time	t _f		-	10	-	nS	
Total Gate Charge	Qg	\/ -40\/1 -20A	-	51	-	nC	
Gate-Source Charge	Q _{gs}	V_{DS} =10V, I_{D} =30A, V_{GS} =10V	-	14	-	nC	
Gate-Drain Charge	Q _{gd}	V _{GS} =10V	-	11	-	nC	
Drain-Source Diode Characteristics	·						
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =24A	-	-	1.2	V	
Diode Forward Current (Note 2)	Is		-	-	80	Α	
Reverse Recovery Time	t _{rr}	TJ = 25°C, IF = 30A	-	32	50	nS	
Reverse Recovery Charge	Qrr	di/dt = 100A/µs ^(Note3)	-	12	20	nC	
Forward Turn-On Time	t _{on}	Intrinsic turn-on time is negligible (turn-on is dominated by LS+LD)				y LS+LD)	

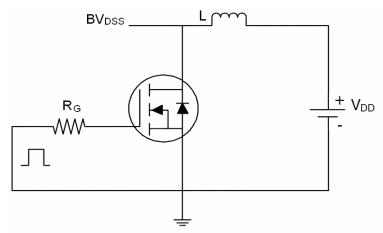
Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- **2.** Surface Mounted on FR4 Board, $t \le 10$ sec.
- 3. Pulse Test: Pulse Width ≤ 300µs, Duty Cycle ≤ 2%.
- 4. Guaranteed by design, not subject to production
- **5.** EAS condition: Tj=25 $^{\circ}$ C,V_{DD}=15V,V_G=10V,L=0.5mH,Rg=25 Ω , I_{AS}=35A

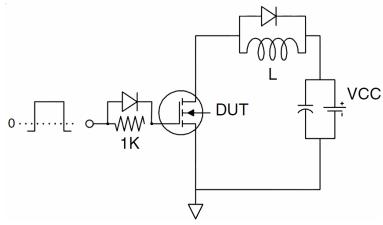
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Test Circuit

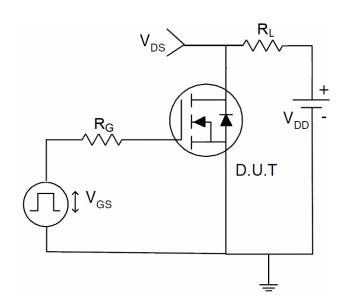
1) E_{AS} Test Circuits



2) Gate Charge Test Circuit:

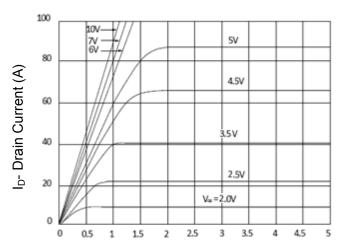


3) Switch Time Test Circuit:

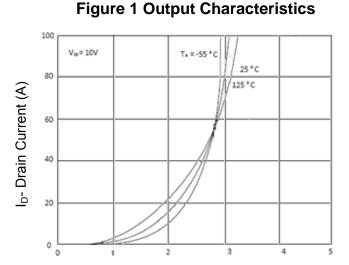




Typical Electrical and Thermal Characteristics (Curves)



Vds Drain-Source Voltage (V)



Vgs Gate-Source Voltage (V)
Figure 2 Transfer Characteristics

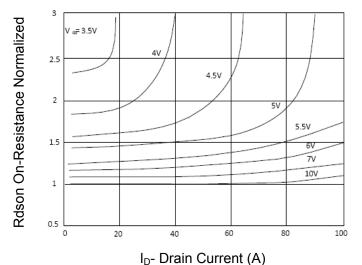


Figure 3 Rdson- Drain Current

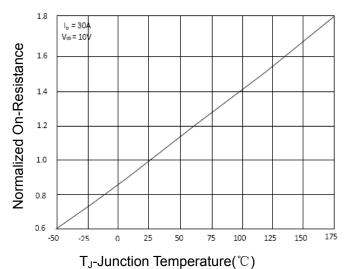
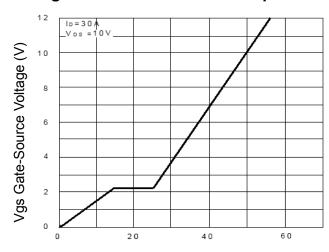
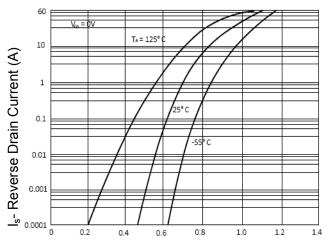


Figure 4 Rdson-Junction Temperature



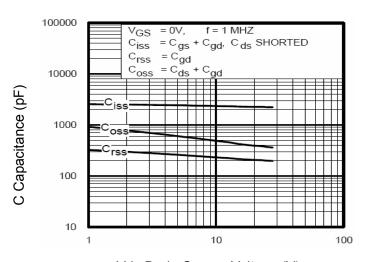
Qg Gate Charge (nC)
Figure 5 Gate Charge



Vsd Source-Drain Voltage (V)

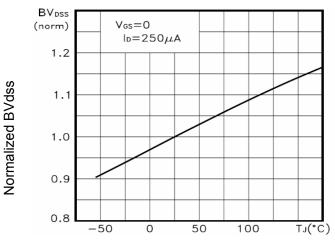
Figure 6 Source- Drain Diode Forward





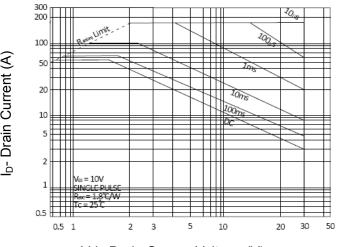
Vds Drain-Source Voltage (V)

Figure 7 Capacitance vs Vds



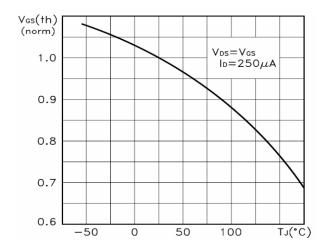
 T_J -Junction Temperature(${}^{\circ}\mathbb{C}$)

Figure 9 BV_{DSS} vs Junction Temperature



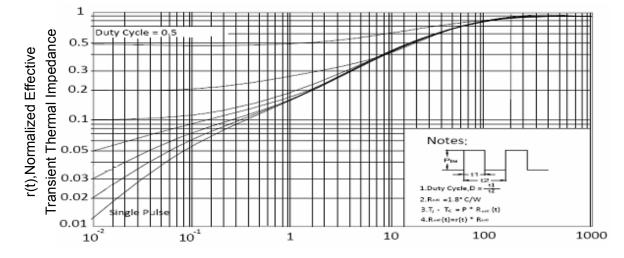
Vds Drain-Source Voltage (V)

Figure 8 Safe Operation Area



T_J-Junction Temperature(°C)

Figure 10 V_{GS(th)} vs Junction Temperature



Square Wave Pluse Duration(sec)

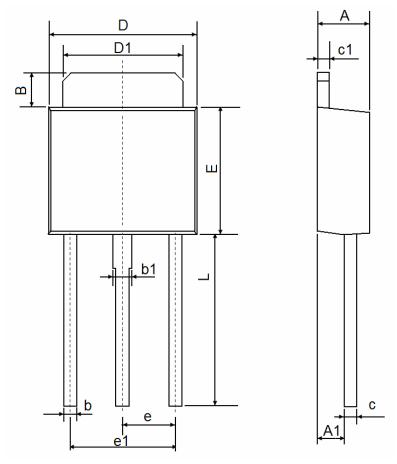
Figure 11 Normalized Maximum Transient Thermal Impedance



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TO-251 Package Information



Combal	Dimensions	In Millimeters	Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
Α	2.200	2.400	0.087	0.094	
A1	1.050	1.350	0.042	0.054	
В	1.350	1.650	0.053	0.065	
b	0.500	0.700	0.020	0.028	
b1	0.700	0.900	0.028	0.035	
С	0.430	0.580	0.017	0.023	
c1	0.430	0.580	0.017	0.023	
D	6.350	6.650	0.250	0.262	
D1	5.200	5.400	0.205	0.213	
E	5.400	5.700	0.213	0.224	
е	2.300 TYP.		0.091 TYP.		
e1	4.500	4.700	0.177	0.185	
L	7.500	7.900	0.295	0.311	



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